

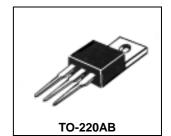
# **Schottky Barrier Power Rectifiers**

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

- \* Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \* Low Power Loss & High efficiency.
- \* 150 Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory

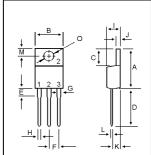
#### SCHOTTKY BARRIER RECTIFIERS

20 AMPERES 70-100 VOLTS



## **MAXIMUM RATINGS**

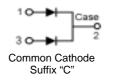
Characteristic	Symbol	S20C				11
		70CE	80CE	90CE	100CE	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	70	80	90	100	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	49	56	63	70	٧
Average Rectifier Forward Current Total Device (Rated V <sub>R</sub> ),T <sub>C</sub> =100	I <sub>F(AV)</sub>	10 20				А
Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz)	I <sub>FM</sub>	20			А	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I <sub>FSM</sub>	200			А	
Operating and Storage Junction Temperature Range	$T_J,T_STG$	-65 to +150				



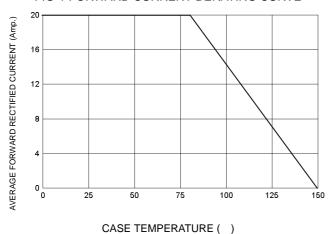
DIM	MILLIMETERS				
	MIN	MAX			
Α	14.68	15.32			
В	9.78	10.42			
С	5.02	6.52			
D	13.06	14.62			
Ε	3.57	4.07			
F	2.42	2.66			
G	1.12	1.36			
Н	0.72	0.96			
ı	4.22	4.98			
J	1.14	1.38			
K	2.20	2.98			
L	0.33	0.55			
M	2.48	2.98			
0	3.70	3.90			

# **ELECTRIAL CHARACTERISTICS**

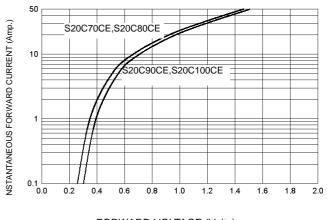
Characteristic	Symbol	S20C				l lm!t
Characteristic		70CE	80CE	90CE	100CE	Unit
Maximum Instantaneous Forward Voltage ( $I_F = 10 \text{ Amp } T_C = 25$ ) ( $I_F = 10 \text{ Amp } T_C = 125$ )	V <sub>F</sub>	0.75 0.68		0.80 0.73		٧
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25$ ) ( Rated DC Voltage, $T_C = 125$ )	I <sub>R</sub>	0.5		-		mA







#### FIG-2 TYPICAL FORWARD CHARACTERISITICS



#### FORWARD VOLTAGE (Volts)

#### FIG-3 TYPICAL REVERSE CHARACTERISTICS

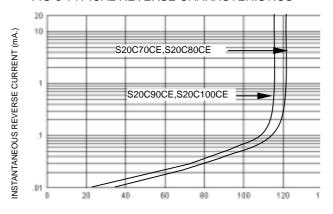
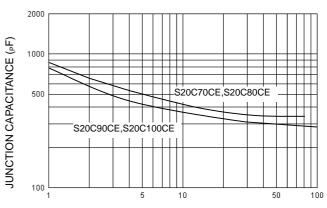
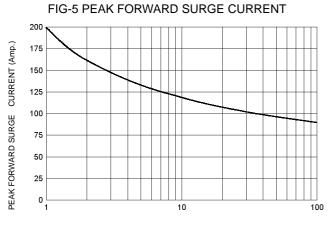


FIG-4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE (Volts)

PERCENT OF RATED REVERSE VOLTAGE (%)



NUMBER OF CYCLES AT 60 Hz



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